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## Conductance and gating effects at sputtered oxide interfaces

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### Citation

Yin, C. (2019, July 3). *Conductance and gating effects at sputtered oxide interfaces*. *Casimir PhD Series*. Retrieved from <https://hdl.handle.net/1887/74527>

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**Title:** Conductance and gating effects at sputtered oxide interfaces

**Issue Date:** 2019-07-03

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